



# PEMD10

50 V, 100 mA NPN/PNP resistor-equipped double transistor;  
R1 = 2.2 k $\Omega$ , R2 = 47 k $\Omega$

18 January 2023

Product data sheet

## 1. General description

NPN/PNP double Resistor-Equipped Transistor (RET) in an ultra small and flat lead SOT666 Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PEMH10

PNP/PNP complement: PEMB10

## 2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

## 3. Applications

- Low current peripheral driver
- Controlling IC inputs
- Replaces general-purpose transistors in digital applications

## 4. Quick reference data

Table 1. Quick reference data

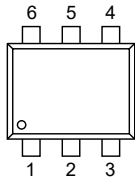
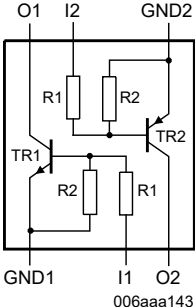
Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
<b>Per transistor; for the PNP transistor (TR2) with negative polarity, where applicable</b>							
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	50	V	
I <sub>O</sub>	output current		-	-	100	mA	
R1	bias resistor 1 (input)		[1]	1.54	2.2	2.86	k $\Omega$
R2/R1	bias resistor ratio		[1]	17	21	26	

[1] See section "Test information" for resistor calculation and test conditions.

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 2.2 kΩ, R2 = 47 kΩ

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	 <p style="text-align: center;"><b>SOT666</b></p>	 <p style="text-align: center;">006aaa143</p>
2	I1	input (base) TR1		
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	I2	input (base) TR2		
6	O1	output (collector) TR1		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
<a href="#">PEMD10</a>	SOT666	plastic, surface-mounted package; 6 leads; 0.5 mm pitch; 1.6 mm x 1.2 mm x 0.55 mm body	<a href="#">SOT666</a>

## 7. Marking

Table 4. Marking codes

Type number	Marking code
PEMD10	D1

## 8. Limiting values

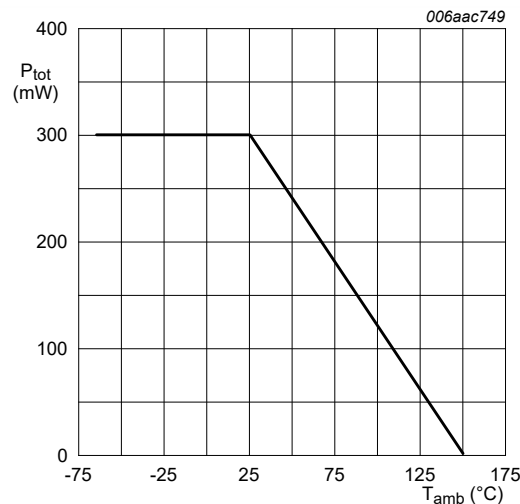
**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
<b>Per transistor; for the PNP transistor (TR2) with negative polarity, where applicable</b>					
V <sub>CBO</sub>	collector-base voltage	open emitter	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	5	V
V <sub>I</sub>	input voltage	positive (input voltage TR1)	-	12	V
		negative (Input voltage TR1)	-	-5	V
		positive (input voltage TR2)	-	5	V
		negative (Input voltage TR2)	-	-12	V
I <sub>O</sub>	output current		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1] [2]	200	mW
<b>Per device</b>					
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1] [2]	300	mW
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	150	°C
T <sub>stg</sub>	storage temperature		-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.



FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint

**Fig. 1. Per device: Power derating curve**

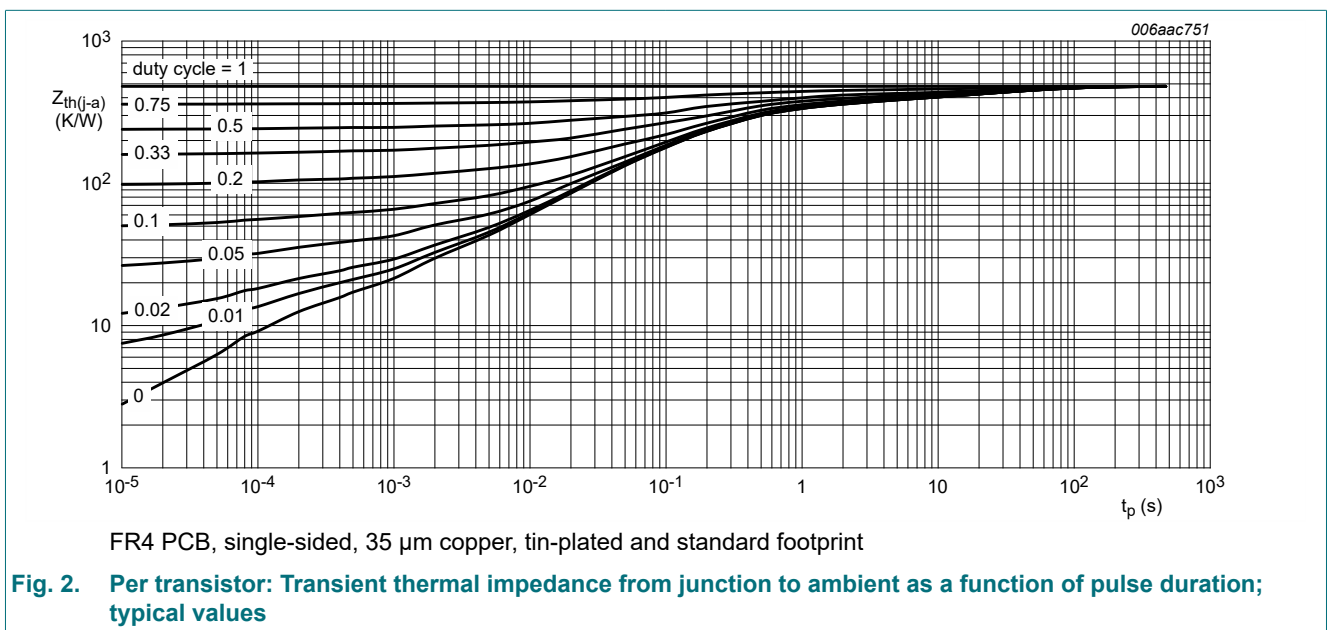
## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per transistor</b>						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	625	K/W
<b>Per device</b>						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] [2]	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.



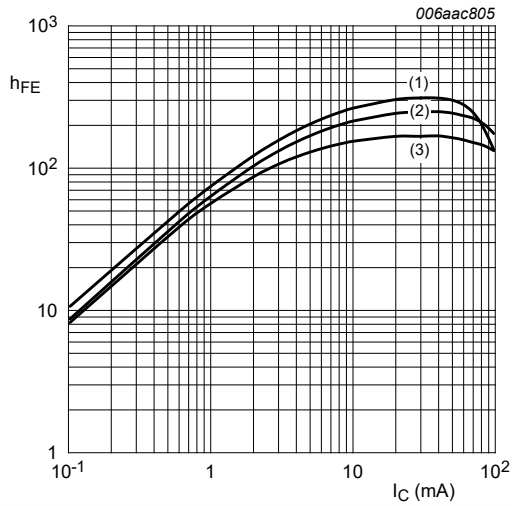
## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
<b>Per transistor; for the PNP transistor (TR2) with negative polarity, where applicable</b>							
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \mu\text{A}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	50	-	-	V	
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}$ ; $I_B = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	50	-	-	V	
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 50 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	100	nA	
$I_{CEO}$	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$ ; $I_B = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	100	nA	
		$V_{CE} = 30 \text{ V}$ ; $I_B = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ ; $T_j = 150 \text{ }^\circ\text{C}$	-	-	5	$\mu\text{A}$	
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 5 \text{ V}$ ; $I_C = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	180	$\mu\text{A}$	
$h_{FE}$	DC current gain	$V_{CE} = 5 \text{ V}$ ; $I_C = 10 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	100	-	-		
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 5 \text{ mA}$ ; $I_B = 0.25 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	100	mV	
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}$ ; $I_C = 100 \mu\text{A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	0.6	0.5	V	
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}$ ; $I_C = 5 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	1.1	0.75	-	V	
R1	bias resistor 1 (input)		[1]	1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		[1]	17	21	26	
<b>TR1 (NPN)</b>							
$C_c$	collector capacitance	$V_{CB} = 10 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $i_e = 0 \text{ A}$ ; $f = 1 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	2.5	pF	
$f_T$	transition frequency	$V_{CE} = 5 \text{ V}$ ; $I_C = 10 \text{ mA}$ ; $f = 100 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	[2]	230	-	MHz	
<b>TR2 (PNP)</b>							
$C_c$	collector capacitance	$V_{CB} = -10 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $i_e = 0 \text{ A}$ ; $f = 1 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	3	pF	
$f_T$	transition frequency	$V_{CE} = -5 \text{ V}$ ; $I_C = -10 \text{ mA}$ ; $f = 100 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	[2]	180	-	MHz	

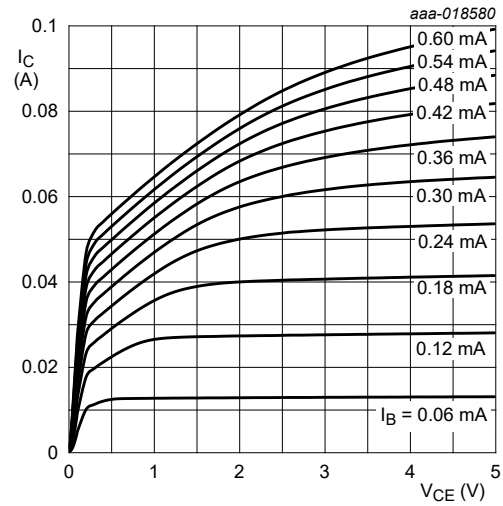
[1] See section "Test information" for resistor calculation and test conditions.

[2] Characteristics of built-in transistor



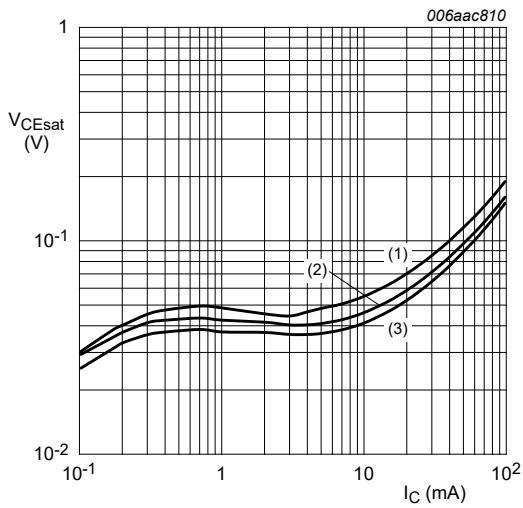
$V_{CE} = 5\text{ V}$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -40\text{ °C}$

**Fig. 3. NPN transistor: DC current gain as a function of collector current; typical values**



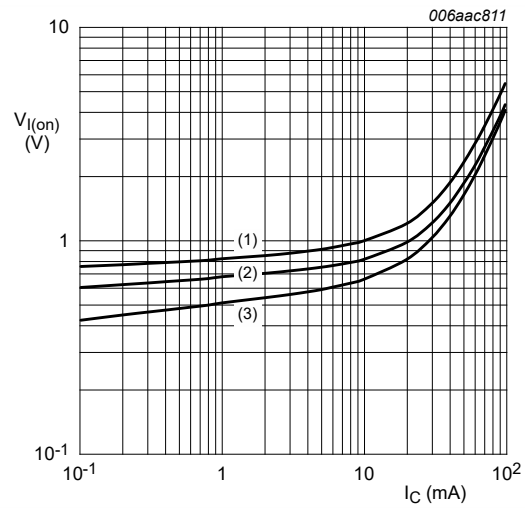
$T_{amb} = 25\text{ °C}$

**Fig. 4. NPN transistor: Collector current as a function of collector-emitter voltage; typical values**



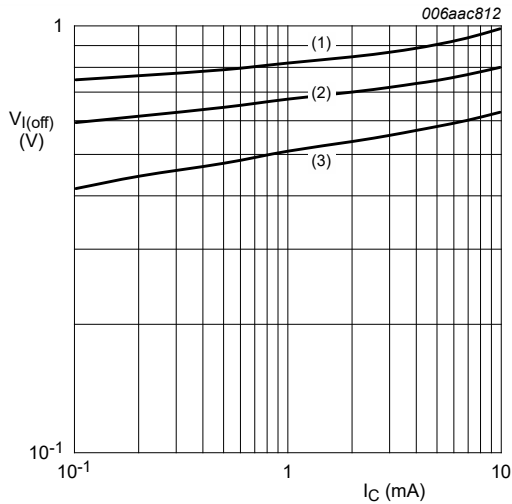
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -40\text{ °C}$

**Fig. 5. NPN transistor: Collector-emitter saturation voltage as a function of collector current; typical values**



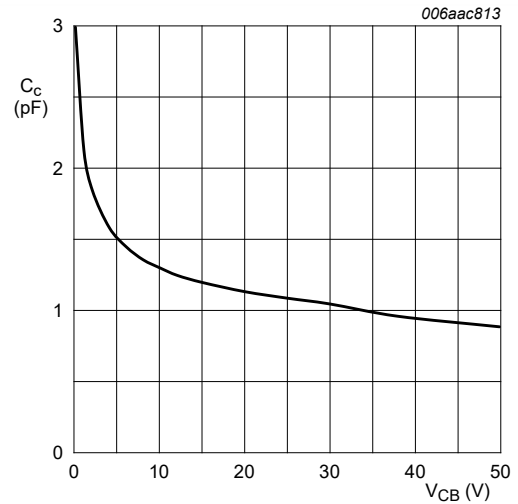
$V_{CE} = 0.3\text{ V}$   
 (1)  $T_{amb} = -40\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = 100\text{ °C}$

**Fig. 6. NPN transistor: On-state input voltage as a function of collector current; typical values**



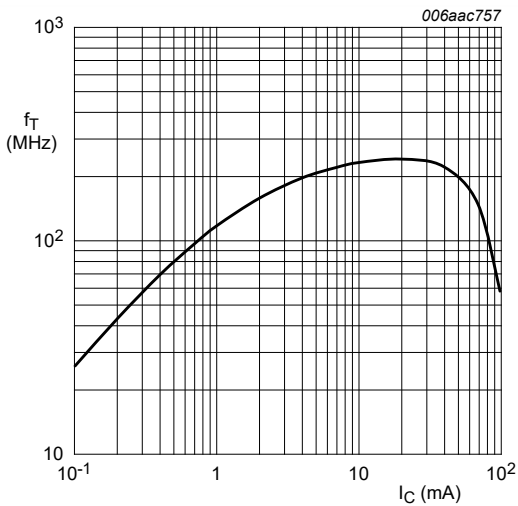
$V_{CE} = 5\text{ V}$   
 (1)  $T_{amb} = -40\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = 100\text{ °C}$

**Fig. 7. NPN transistor: Off-state input voltage as a function of collector current; typical values**



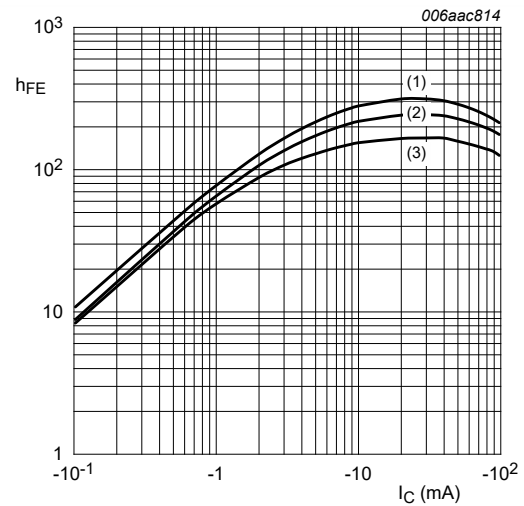
$f = 1\text{ MHz}; T_{amb} = 25\text{ °C}$

**Fig. 8. NPN transistor: Collector capacitance as a function of collector-base voltage; typical values**



$V_{CE} = 5\text{ V}; T_{amb} = 25\text{ °C}$

**Fig. 9. NPN transistor: Transition frequency as a function of collector current; typical values of built-in transistor**



$V_{CE} = -5\text{ V}$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -40\text{ °C}$

**Fig. 10. PNP transistor: DC current gain as a function of collector current; typical values**

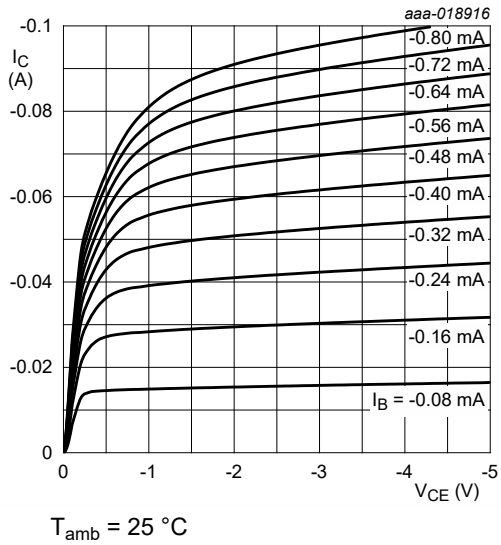


Fig. 11. PNP transistor: Collector current as a function of collector-emitter voltage; typical values

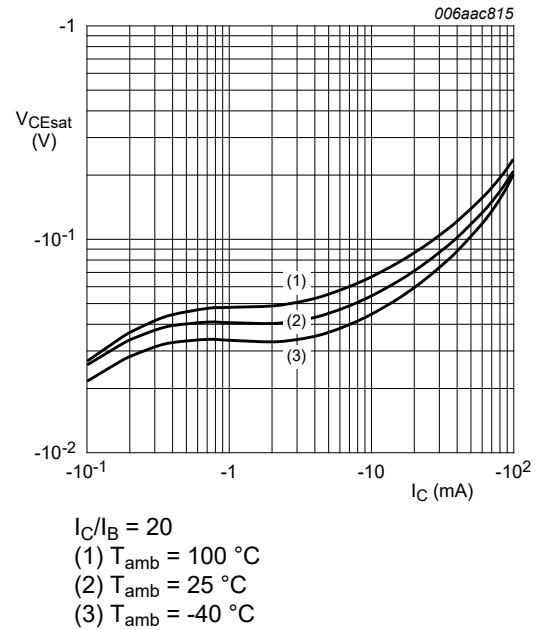


Fig. 12. PNP transistor: Collector-emitter saturation voltage as a function of collector current; typical values

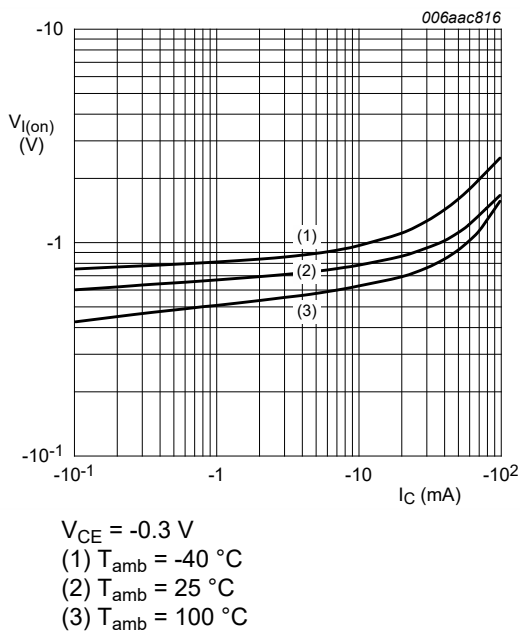


Fig. 13. PNP transistor: On-state input voltage as a function of collector current; typical values

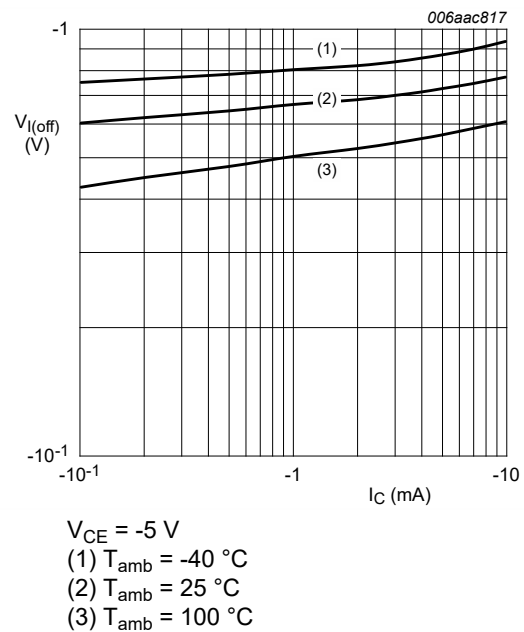
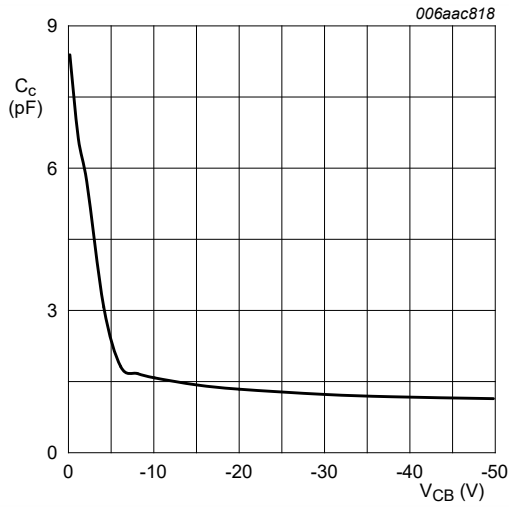
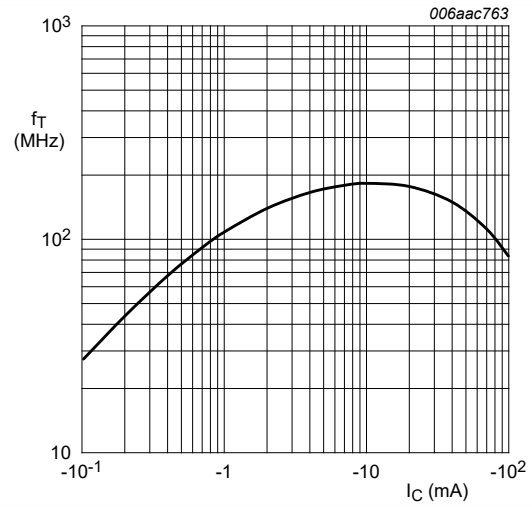


Fig. 14. PNP transistor: Off-state input voltage as a function of collector current; typical values



$f = 1 \text{ MHz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$

**Fig. 15. PNP transistor: Collector capacitance as a function of collector-base voltage; typical values**



$V_{\text{CE}} = -5 \text{ V}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$

**Fig. 16. PNP transistor: Transition frequency as a function of collector current; typical values of built-in transistor**

## 11. Test information

### Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R_2}{R_1} = \frac{V(I_3)}{R_1 \cdot I_3} - 1$$

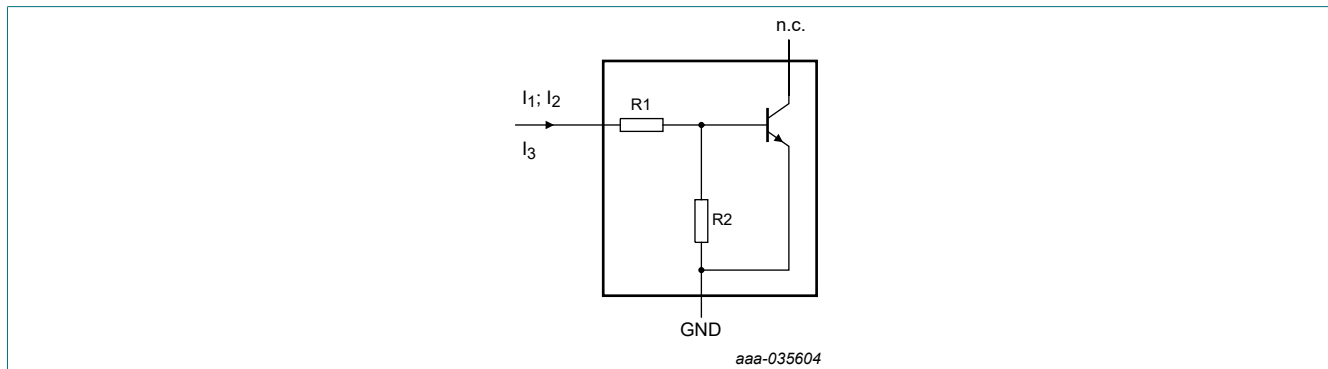


Fig. 17. TR1 (NPN): Resistor test circuit

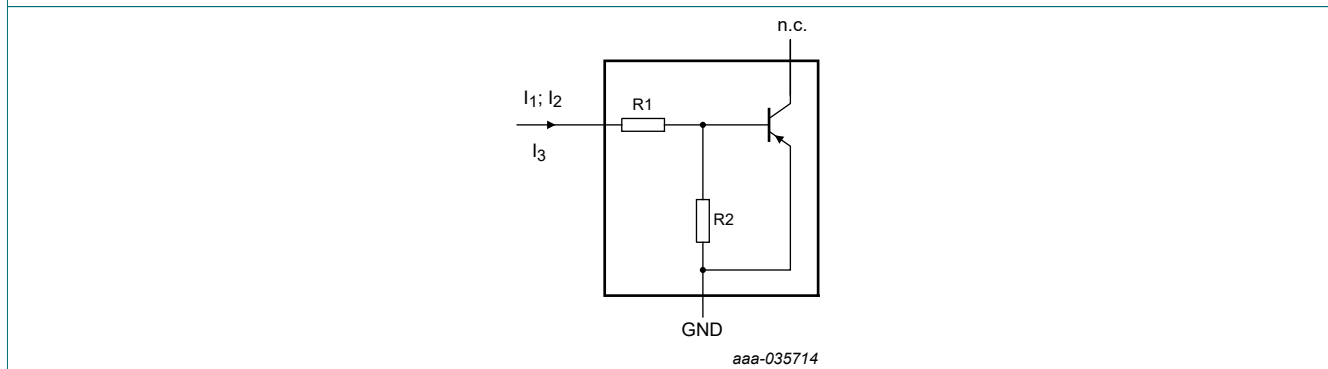


Fig. 18. TR2 (PNP): Resistor test circuit

### Resistor test conditions

Table 8. Resistor test conditions

PEMD10	R1 (kΩ)	R2 (kΩ)	Test conditions		
			I <sub>1</sub>	I <sub>2</sub>	I <sub>3</sub>
TR1 (NPN)	2.2	47	600 μA	700 μA	-100 μA
TR2 (PNP)	2.2	47	-600 μA	-700 μA	100 μA

## 12. Package outline

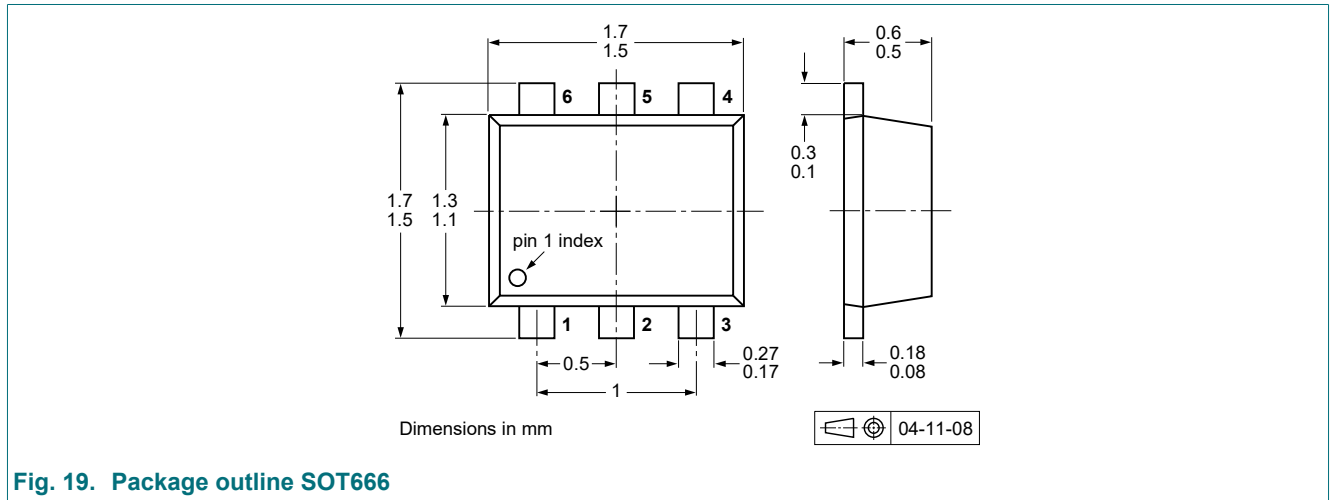


Fig. 19. Package outline SOT666

## 13. Soldering

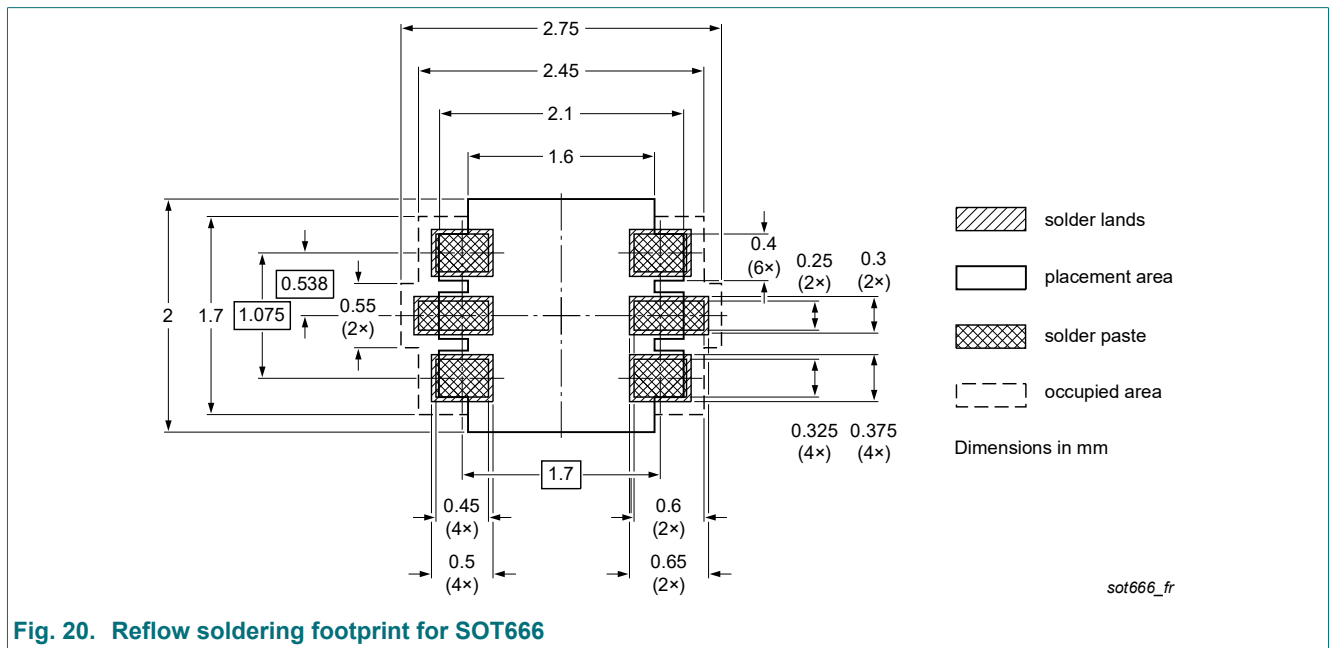


Fig. 20. Reflow soldering footprint for SOT666

## 14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PEMD10 v.7	20230118	Product data sheet	-	PEMD10_PUMD10 v.6
Modifications:	<ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Family data sheet reduced to single type data sheet.</li> <li>Product(s) changed to non-automotive qualification.</li> </ul>			
PEMD10_PUMD10 v.6	20120104	Product data sheet	-	PEMD10_PUMD10 v.5
PEMD10_PUMD10 v.5	20040415	Product data sheet	-	PEMD10_PUMD10 v.4
PEMD10_PUMD10 v.4	20031104	Product specification	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Date of release: 18 January 2023

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